

CT815x Integrated Omnipolar TMR Analog Sensor

Features

- Sensitivity and Magnetic Field Range:
 S = 50 mV/V/mT, BANA = ±8.0 mT
- Analog Output Mode Current Consumption is ~1.3 µA
 Current Consumption in Digital Output Only: ~150
 - nA @ V_{DD} = 1.8 V and fs = 12.5 Hz
- Supply Voltage Range: 1.7 V to 5.5 V
- Sensor Polarity: Omnipolar
- Sample and Hold Analog Output @ fs = 100 Hz
- Dual Analog and Digital Output Operation Capability
 Digital Output is Push-pull
- Under-Voltage Lockout (UVLO)
- Package Options:
 - o 3-Lead SOT23
 - o 5-lead SOT23
 - \circ ~ 4-lead LGA, 1.45 \times 1.45 \times 0.45 mm ~

Applications

- IoT Devices
- Smartphones, Tablets and Laptops
- Door or Lid Closure
- Tamper-proofing for Utility Smart Meters
- Fluid Level Sensing/Detection
- Proximity Detection
- Motor Controllers
- Gimbals for Camera Systems in Drones/UAVs
- Industrial Machinery/Robots
- Medical Devices

Product Description

The CT815x series of Tunnel Magnetoresistance (TMR) analog sensors (with option for digital latch output) are designed for consumer and industrial applications. It is based on Crocus Technology's patented XtremeSense® TMR technology with integrated CMOS process to provide a monolithic solution for superior sensing performance. Also, the CT815x analog sensors offer magnetic operation over temperature.

The CT815x is an analog sensor product family that provides a linear sample and hold (S&H) analog output voltage with a sampling frequency of 100 Hz.

CT8152 is a TMR sensor that combines both analog and digital outputs in a single chip. It uses the digital output to turn on the analog output so that it can remain in an ultralow power state until the analog mode is enabled. When the B_{RP} is triggered in digital mode, the analog output function will start operating.

This product family has very low power consumption as low as 1.3 μ A in analog output mode and 150 nA in digital output mode which makes it ideal for battery-operated products where minimal current consumption is required.

For applications that require a very small form factor and low profile, the CT815x sensors are assembled in a 4-lead LGA package. The CT8150 is also available in an industry standard 3-lead SOT-23 package while CT8152 is offered in a 5-lead SOT23 package to support high volume manufacturing.

Ordering Information

Part Number	Operating Temperature Range	Sensor Type	Analog Output	Digital Output (B _{OP} /B _{RP})	S (mV/V/mT)	Range (mT)	Package	Packing Method
CT8150PC-IS3	-40°C to +85°C	Omnipolar	Yes	No	50	±8.0	3-lead	Tape &
CT8150PC-HS3	-40°C to +125°C	Ommpolar		NO	50	10.0	SOT23	Reel
CT8150PC-IL4	-40°C to +85°C	- Omnipolar Yes	No	50	±8.0	4-lead	Tape &	
CT8150PC-HL4	-40°C to +125°C	Omnipolar		INO	50	±0.0	LGA	Reel
CT8152PC-IS5	-40°C to +85°C	Omnipolar Yes	Vee	Yes	50	10.0	5-lead	Tape &
CT8152PC-HS5	-40°C to +125°C		(6 mT/4 mT) 50	50	±8.0	SOT23	Reel	
CT8152PC-IL4	-40°C to +85°C	Omninglar	Vee	Yes	50	10.0	4-lead	Tape &
CT8152PC-HL4	-40°C to +125°C	Omnipolar	Yes	(6 mT/4 mT)	50	±8.0	LGA	Reel

Block Diagram

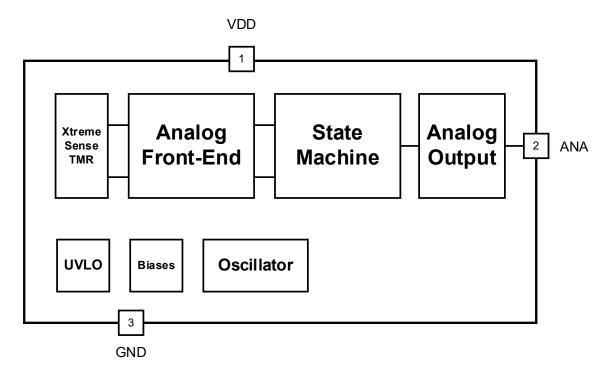


Figure 1. CT8150 with Analog Output Block Diagram

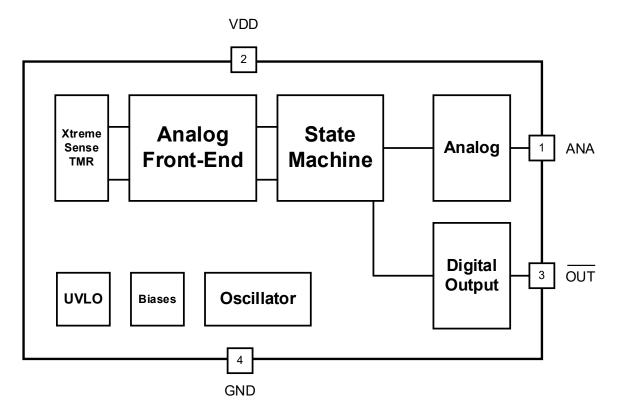


Figure 2. CT8152 with Dual Analog and Digital Outputs Block Diagram

SOT23 Pin Configuration

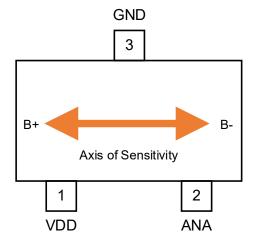


Figure 3. CT8150: 3-Lead SOT23 Package for Analog Output

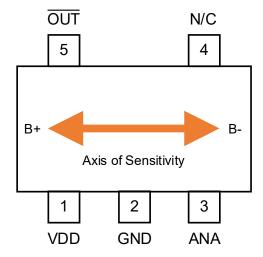


Figure 4. CT8152: 5-Lead SOT23 Package for Analog Output

Pin # for CT8150	Pin # of CT8152	Pin Name	Pin Description
1	1	VDD	Supply Voltage
2		ANA	Analog Output
	2	GND	Ground
3		GND	Ground
	3	ANA	Analog Output
-	4	N/C	No Connect
-	5	OUT	Output Signal (Active LOW)

Pin Definitions

CT815x

LGA Pin Configuration

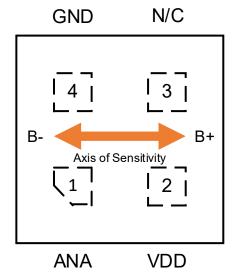


Figure 5. CT8150: 4-Lead LGA Package with Analog Output, Top View

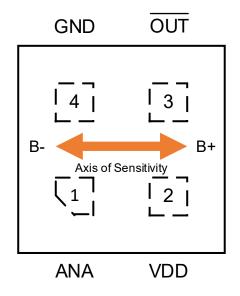


Figure 6. CT8152: 4-Lead LGA Package with Analog and Digital Outputs, Top View

Pin #	Pin Name for CT8150	Pin Name for CT8152	Pin Description
1	ANA	ANA	Analog Output
2	VDD	VDD	Supply Voltage
3	N/C		No Connect
		OUT	Output Signal (Active LOW)
4	GND	GND	Ground

Pin Definitions

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the CT815x. The CT815x products may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Parameter			Unit
V _{DD}	Supply Voltage		-0.3	6.0	V
V _{OUT_PP}	Push-pull Output (Active L	_OW)	-0.3	V _{DD} + 0.3*	V
Vi/o	Input/Output Pins Maximu	Input/Output Pins Maximum Voltage		V _{DD} + 0.3*	V
I _{IN} / I _{OUT}	Input and Output Current			±20.0	mA
B _{MAX}	Maximum External Magnetic Field @ T _A = +25°C			±200	mT
	Electrostatia Discharge	Human Body Model (HBM) per JESD22-A114	±4.0		
ESD	Electrostatic Discharge Protection Level	Charged Device Model (CDM) per JESD22- C101	±0.5		kV
TJ	Junction Temperature		-40	+150	°C
Tstg	Storage Temperature		-65	+150	°C
T∟	Lead Soldering Temperate	ure, 10 Seconds		+260	°C

*The lower of V_{DD} + 0.3 V or 6.0 V.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual operation of the CT815x. Recommended operating conditions are specified to ensure optimal performance to the specifications. Crocus Technology does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Тур.	Max.	Unit	
V _{DD}	Supply Voltage Range	1.7	3.3	5.5	V	
Vout	OUT Voltage Range	0		V _{DD}	V	
B _{OP}	Operating Magnetic Flux			30	mT	
Ιουτ	OUT Current			±3.0	mA	
Свур	Bypass Capacitor		1.0		μF	
т.	Operating Ambient Temperature	Industrial	-40	+25	+85	°C
TA	Operating Ambient Temperature	Extended Industrial	-40	+25	+125	
TJ	Operating Junction Temperature		-40		+125	°C

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout and is determined in accordance to JEDEC standard JESD51 for a four (4) layer 2s2p FR-4 printed circuit board (PCB) with 2 oz. of copper (Cu). Special attention must be paid to not exceed junction temperature $T_{J(MAX)}$ at a given ambient temperature T_A .

Symbol	Parameter		Тур.	Max.	Unit
θја	Junction-to-Ambient Thermal Resistance, SOT23-3		202		°C/W
θја	Junction-to-Ambient Thermal Resistance, LGA-4		165		°C/W

Electrical Specifications

General Parameters

Unless otherwise specified: V_{DD} = 1.7 V to 5.5 V, C_{BYP} = 1.0 μ F and T_A = -40°C to +125°C. Typical values are V_{DD} = 3.3 V and T_A = +25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit		
Timings	Timings							
ton	Power-On Time ⁽¹⁾	$V_{DD} \ge 1.7 \text{ V}$		50	75	μs		
t ACTIVE	Active Mode Time (1)			2.6		μs		
Protectio	n							
Mana	Under-Voltage Lockout (1)	Rising VDD		1.60	1.64	V		
Vuvlo		Falling VDD	1.44	1.53		V		
Vuv_hys	UVLO Hysteresis ⁽¹⁾			70		mV		

(1) Guaranteed by design and characterization; not tested in production.

Typical Timing Characteristics

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

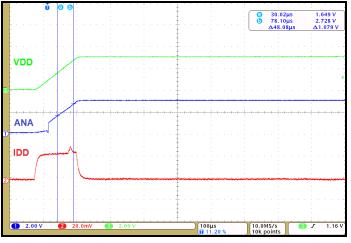


Figure 7. Power-On Time for Analog Output

CT8150PC Electrical & Magnetic Specifications

Unless otherwise specified: V_{DD} = 1.7 V to 5.5 V, C_{BYP} = 1.0 μ F and T_A = -40°C to +125°C. Typical values are V_{DD} = 3.3 V and T_A = +25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
DD(AVG)	Average Supply Current	t ≥ 10 s		1.5	5.0	μA
IDD(AVG)_1.8V	Average Supply Current @ V _{DD} = 1.8 V	$t \ge 10 \text{ s}, V_{DD} = 1.8 \text{ V}$		1.3	3.0	μA
fs	Sampling Frequency		60	100	140	Hz
tidle	Idle Mode Time	fs = 100 Hz	7.1	10.0	16.7	ms
Idrv(max)	Maximum Drive Capability	$\Delta V_{OUT} \le 10 \text{ mV}$	-10		+10	μA
CL	Output Capacitive Load ⁽¹⁾				10	pF
Bana	Analog Output Magnetic Field		±5.4	±8.0	±10.0	mT
Vana	Analog Output Voltage Range		$0.1 imes V_{DD}$		$0.9 \times V_{\text{DD}}$	V
Voq	Voltage Output Quiescent		45	50	55	% V _{DD}
S	Sensitivity		35	50	65	mV/V/mT

(1) Guaranteed by design and characterization; not tested in production.

Typical Magnetic Characteristics for CT8150PC

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 μ F (unless otherwise specified)

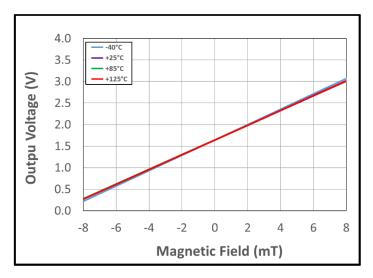


Figure 8. Output Voltage vs. Magnetic Field over Temperature at V_{DD} = 3.3 V.

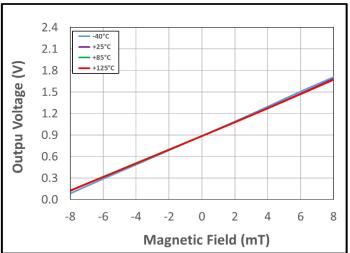
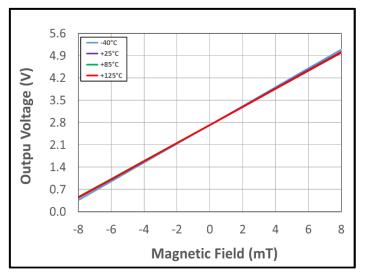
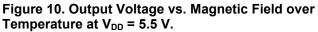


Figure 9. Output Voltage vs. Magnetic Field over Temperature at V_{DD} = 1.8 V.





Typical Electrical Characteristics for CT8150PC

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

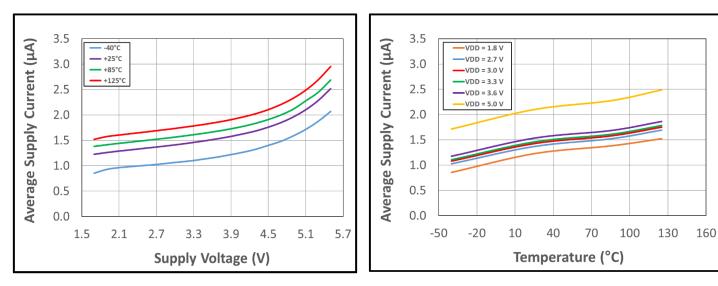
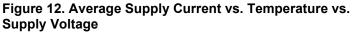


Figure 11. Average Supply Current vs. Supply Voltage vs. Temperature



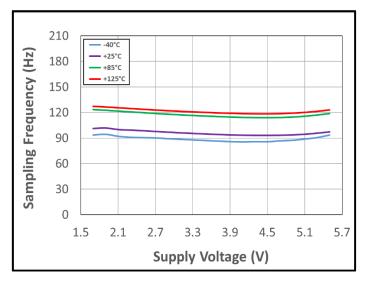


Figure 13. Sampling Frequency vs. Supply Voltage vs. Temperature

CT8152PC Electrical & Magnetic Specifications

Unless otherwise specified: V_{DD} = 1.7 V to 5.5 V, C_{BYP} = 1.0 μ F and T_A = -40°C to +125°C. Typical values are V_{DD} = 3.3 V and T_A = +25°C.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Analog Out	tput Mode (Digital Mode is Of	N)				
Idd(AVG)	Average Supply Current	t ≥ 10 s, Analog and Digital Modes ON		1.5	5.0	μA
DD(AVG)_1.8V	Average Supply Current @ V _{DD} = 1.8 V	$t \ge 10 \text{ s}, V_{DD} = 1.8 \text{ V},$ Analog and Digital Modes ON		1.3	3.0	μA
Idrv(max)	Maximum Drive Capability	$\Delta V_{OUT} \le 10 \text{ mV}$	-10		+10	μA
fs_ana	Analog Sampling Frequency		60	100	140	Hz
tidle_ana	Idle Mode Time, Analog Output	fs = 100 Hz	7.1	10.0	16.7	ms
CL	Output Capacitive Load ⁽¹⁾				10	pF
Bana	Analog Output Magnetic Field		±5.4	±8.0	±10.0	mT
Vana	Analog Output Voltage Range		$0.1 \times V_{DD}$		$0.9\times V_{\text{DD}}$	V
Voq	Voltage Output Quiescent		45	50	55	% V _{DD}
S	Sensitivity		35	50	65	mV/V/mT
Digital Out	put Mode					
IDD(AVG)	Average Supply Current	$t \ge 10 s$, Analog Mode OFF		200	900	nA
IDD(AVG)_1.8V	Average Supply Current @ V _{DD} = 1.8 V	$t \ge 10 \text{ s}, V_{DD} = 1.8 \text{ V},$ Analog Mode OFF		150	700	nA
Vон	Output Voltage High OUT (1)		$0.9 \times V_{\text{DD}}$			V
Vol	Output Voltage LOW OUT (1)				$0.1 \times V_{\text{DD}}$	V
Іоит	Current for OUT (1)			±2.0		mA
fs_DIG	Digital Sampling Frequency		7.5	12.5	17.5	Hz
t _{IDLE_DIG}	Idle Mode Time, Digital Output	f _S = 10 Hz	57	80	133	ms
BOPN	Operate Point, B-		4.6	6.0	7.6	mT
BOPS	Operate Point, B+		-7.6	-6.0	-4.6	mT
Brpn	Release Point, B-		2.8	4.0	5.6	mT
B _{RPS}	Release Point, B+		-5.6	-4.0	-2.8	mT
Внузт	Hysteresis		1.0	2.0		mT

(1) Guaranteed by design and characterization; not tested in production.

Typical Magnetic Characteristics for CT8152PC in Digital Mode

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

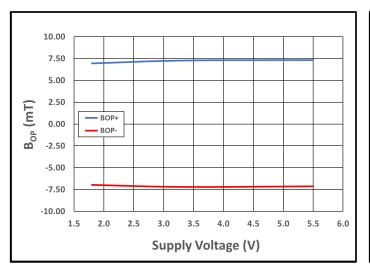


Figure 14. B_{OP-} (Red) and B_{OP+} (Blue) vs. Supply Voltage at T_A = +25°C

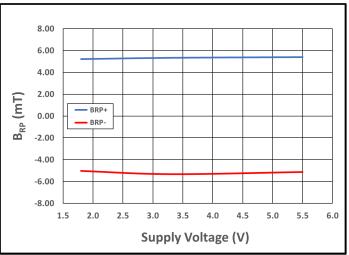
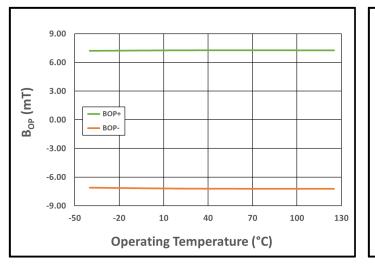
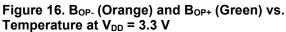
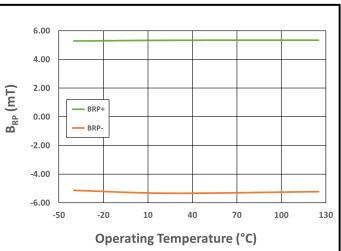
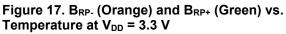


Figure 15. B_{RP-} (Red) and B_{RP+} (Blue) vs. Supply Voltage at T_A = +25°C









Typical Magnetic Characteristics for CT8152PC in Analog Mode

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

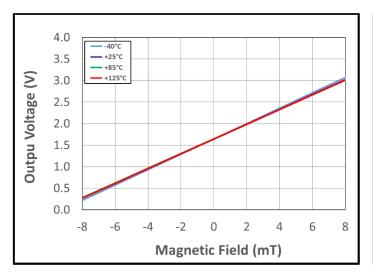


Figure 18. Output Voltage vs. Magnetic Field over Temperature at V_{DD} = 3.3 V.

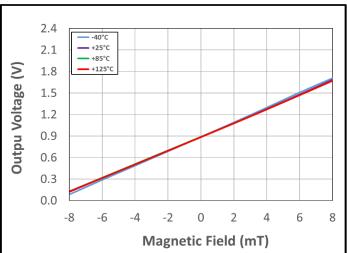
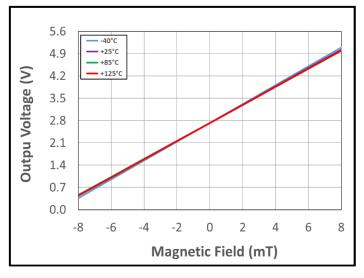
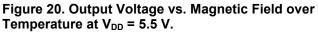


Figure 19. Output Voltage vs. Magnetic Field over Temperature at V_{DD} = 1.8 V.





Typical Electrical Characteristics for CT8152PC in Digital Mode Only

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

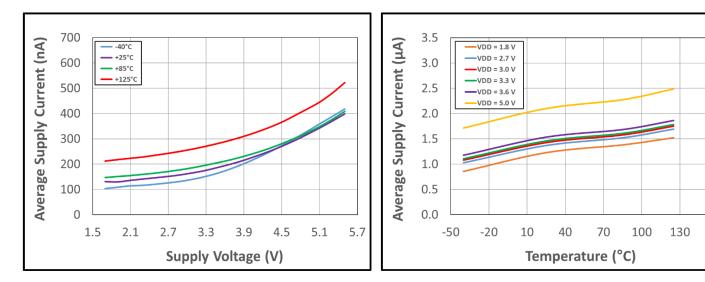


Figure 21. Average Supply Current vs. Supply Voltage vs. Temperature

Figure 22. Average Supply Current vs. Temperature vs. Supply Voltage

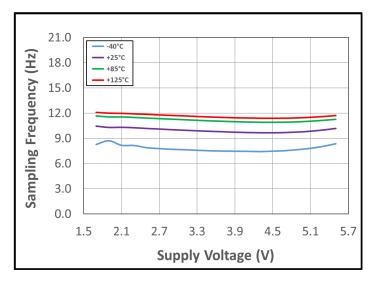


Figure 23. Sampling Frequency vs. Supply Voltage vs. Temperature

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Typical Electrical Characteristics for CT8152PC in Analog & Digital Mode

 V_{DD} = 3.3 V, T_A = +25°C and C_{BYP} = 1.0 µF (unless otherwise specified)

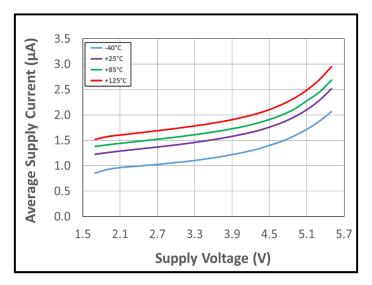


Figure 24. Average Supply Current vs. Supply Voltage vs. Temperature

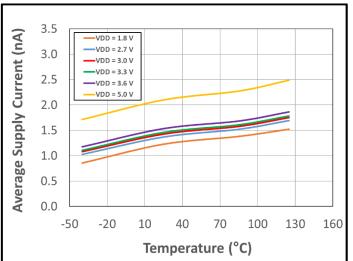


Figure 25. Average Supply Current vs. Temperature vs. Supply Voltage

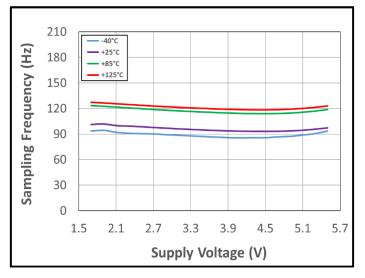


Figure 26. Sampling Frequency vs. Supply Voltage vs. Temperature

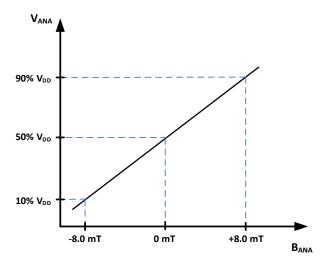
Circuit Description

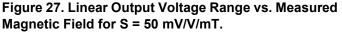
Overview

The CT815x is a product family of TMR analog sensors that provides a linear analog output voltage for a range of magnetic fields. It supports a wide operating voltage range of 1.7 V to 5.5 V enabling it to be used in many applications. Designed to consume a minimal amount of current which is ideal for battery-powered products.

Analog Output Measurement

The CT815x provides a continuous (sample & hold) linear analog output voltage which represents the measured magnetic field. The output voltage range of ANA is 10% of V_{DD} to 90% of V_{DD} which represents the magnetic field from the typical low-end value of -8.0 mT to the maximum magnetic field value of +8.0 mT for a sensitivity of 50 mV/V/mT. A resistor-capacitor (R-C) filter may be implemented on the ANA pin to further lower the noise. Figure 27 illustrates the output voltage range of the ANA pin as a function of the measured current.





Dual Analog & Digital Output Mode

The CT8152 supports both a digital and an analog signal output operating at the same time. The analog output will turn ON when the B_{RP} on the digital output side is triggered at ±8.0 mT and both outputs remain on until the CT8152 is powered OFF. The digital output is configured as a CMOS push-pull and it will start sampling one full cycle/period once dual output mode has been initiated. The analog and digital outputs have a sampling frequency of 80 Hz and 10 Hz respectively and they work independently of one another.

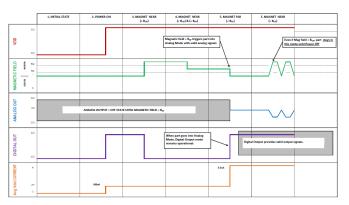


Figure 28. Dual Analog and Digital Mode Operating Conditions of the CT8152.

Under-Voltage Lockout (UVLO)

The Under-Voltage Lock-out protection circuitry of the CT815x is activated when the supply voltage (V_{DD}) falls below 1.53 V. The CT815x remains in a low quiescent state and the ANA and OUT outputs are not valid until V_{DD} rises above the UVLO threshold (1.60 V).

Power-On Time (ton)

The Power-On Time (t_{ON}) of 50 µs is the amount of time required by the CT815x to start up, power-on and acquire the first sample. The chip is fully powered up and operational from the moment the supply voltage passes the rising UVLO point (1.60 V). This time includes the ramp up time and the settling time (within 10% of steadystate voltage under an applied magnetic field) after the power supply have reach the minimum V_{DD}.

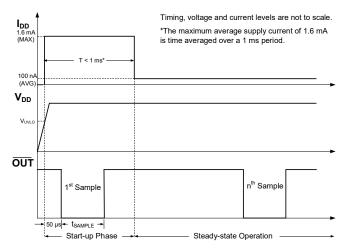


Figure 29. CT815x Power-On Timing Diagram

Applications Information

A decoupling capacitor, C_{BYP} , between the supply voltage (VDD) and ground (GND) is required to lower the noise going into the CT815x products as well as providing isolation from the other circuits. The decoupling capacitor should be placed close to the TMR analog sensor. A typical capacitor value of 1.0 μ F (ceramic) will be sufficient.

For the analog output, a simple RC filter (R = 47 k Ω and C = 100 pF) is recommended on the ANA pin as shown in Figure 30.

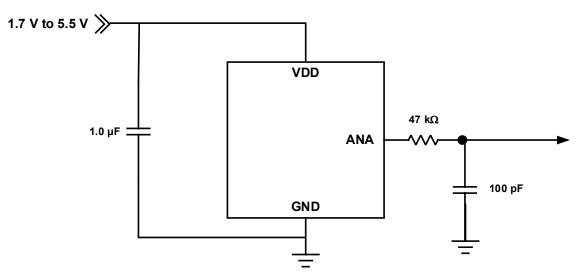


Figure 30. CT8150 Application Block Diagram

For the CT8152, the same bypass capacitor and RF filter of the CT8150 should be implemented.

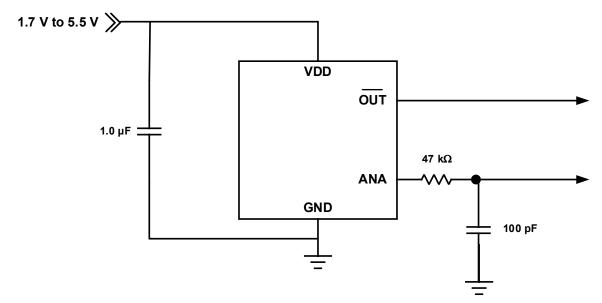
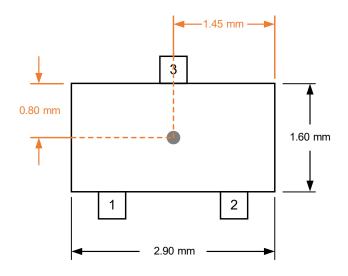


Figure 31. CT8152 Application Block Diagram

Applications Information

The XtremeSense TMR sensor location for the CT815x products are shown in Figure 32, Figure 33 and Figure 34. The dimensions shown in the three figures are typical values.



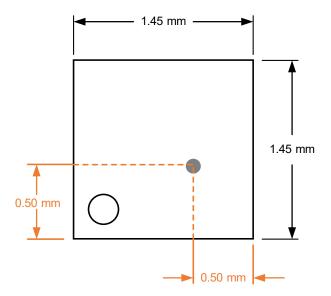


Figure 32. XtremeSense TMR Sensor Location for Figure 33. XtremeSense TMR Sensor Location for CT8150 products in 3-lead SOT23 Package

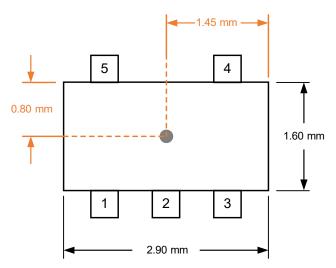
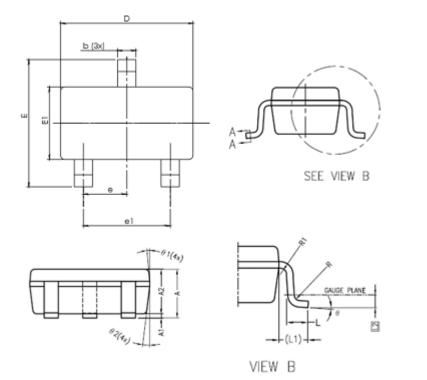
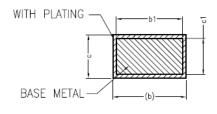


Figure 34. XtremeSense TMR Sensor Location for CT8152 products in 3-lead SOT23 Package

CT815x products in 4-lead LGA Package

SOT23-3 Package Drawing and Dimensions





SECTION A-A

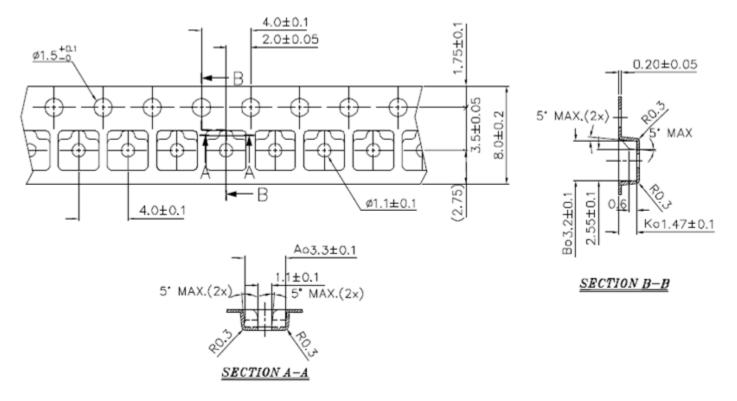
Figure 35. 3-Lead SOT23 Package Drawing

Symbol	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
А	1.05	1.20	1.35			
A1	0.00	0.10	0.15			
A2	1.00	1.10	1.20			
b	0.30	-	0.50			
b1	0.30	0.35	0.45			
С	0.08	-	0.22			
c1	0.08	0.13	0.20			
D	2.80	2.90	3.00			
E	2.60	2.80	3.00			
E1	1.50	1.60	1.70			
е		0.95 BSC				
e1		1.90 BSC				
L	0.35	0.43	0.60			
L1		0.60 REF				
L2		0.25 BSC				
R	0.10	-	-			
R1	0.10	-	0.25			
θ	0°	4°	8°			
θ1	5°	6°	15°			
θ2	5°	8°	15°			

Table 1. CT8150 3-Lead SOT23 Package Dimensions

Crocus Technology provides package drawings as a service to customers considering or planning to use Crocus products in their designs. Drawings may change without notice. Please note the revision and date of the data sheet and contact a Crocus Technology representative to verify or obtain the most recent version. The package specifications do not expand the terms of Crocus Technology's worldwide terms and conditions, specifically the warranty therein, which covers Crocus Technology's products.

SOT23-3 Tape & Pocket Drawing and Dimensions

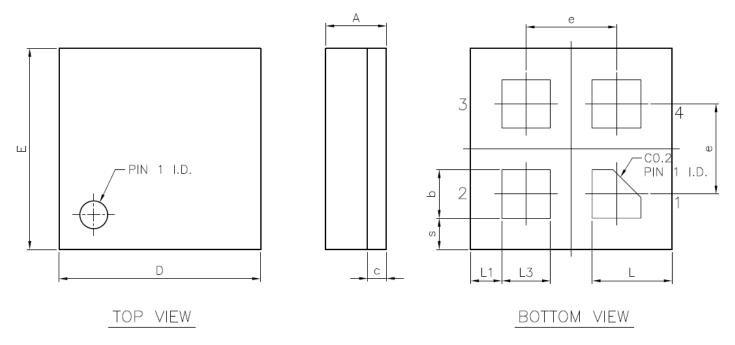


NOTES:

- 1. Material: Conductive Polystyrene
- 2. Dimensions in mm.
- 3. 10 sprocket hole pitch cumulative tolerance ± 0.20 mm.
- 4. Camber bot to exceed 1 mm in 100 mm.
- 5. Pocket position relative to sprocket hole measured as true position of pocket and not pocket hole.
- 6. (S.R. Ω /sq) means surface electric resistivity of the carrier tape.

Figure 36. Tape and Pocket Drawing for 3-lead SOT23 Package

LGA-4 Package Drawing and Dimensions



NOTE:

- 1. All dimensions are in millimeters.
- 2. Pin A1 ID is marked by ink or laser.

Figure 37. 4-Lead LGA Package Drawing

Symbol	Dimensions in Millimeters (mm)						
Symbol	Min.	Тур.	Max.				
A	0.386	0.436	0.486				
b	0.300	0.350	0.400				
С	-	0.136 REF	-				
D	1.400	1.450	1.500				
E	1.400	1.450	1.500				
е	-	0.65	-				
L	0.525	0.575	0.625				
L1	0.175	0.225	0.275				
L3	0.300	0.350	0.400				
S	0.175	0.225	0.275				

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LGA-4 Tape & Pocket Drawing and Dimensions

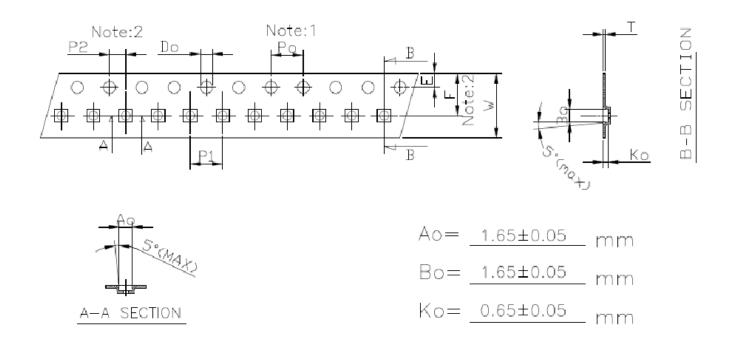


Figure 38. Tape and Pocket Drawing for LGA-4 Package

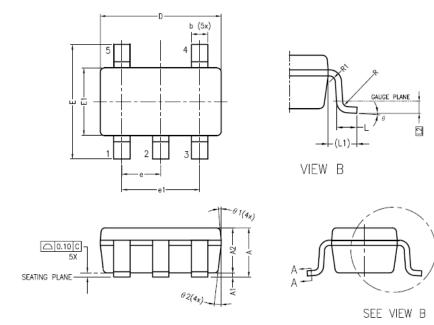
Symbol	Specification
Po	$4.00~\text{mm}\pm0.10~\text{mm}$
P1	$4.00~\text{mm}\pm0.10~\text{mm}$
P2	$2.00~\text{mm}\pm0.05~\text{mm}$
Do	1.50 mm \pm 0.10 mm
D1	$1.10 \text{ mm} \pm 0.05 \text{ mm}$
E	$1.75~\text{mm}\pm0.10~\text{mm}$
F	$3.50~\text{mm}\pm0.05~\text{mm}$
10Po	$40.00~\text{mm}\pm0.10~\text{mm}$
W	$8.00 \text{ mm} \pm 0.20 \text{ mm}$
Т	$0.25~\text{mm}\pm0.02~\text{mm}$

Table 3. LGA-4 Tape and Pocket Dimensions

Notes:

- 1. 10 Sprocket hole pitch cumulative tolerance is ± 0.10 mm.
- 2. Pocket position is relative to sprocket hole measured as true position of pocket and not pocket hole.
- 3. Ao and Bo measured on a place of 0.3 mm above the bottom of the pocket to top surface of the carrier.
- 4. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 5. Carrier camber shall not more than 1 mm per 100 mm through a length of 250 mm.

SOT23-5 Package Drawing and Dimensions



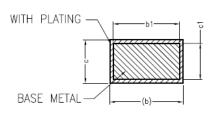




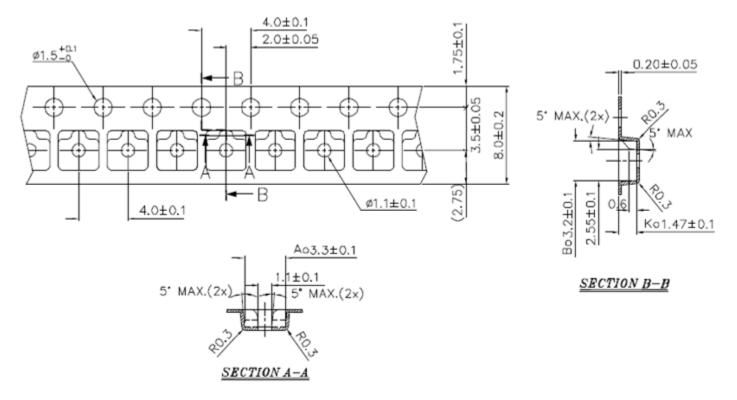
Figure 39. 5-Lead SOT23 Package Drawing

Symbol	Dimensions in Millimeters (mm)					
Symbol	Min.	Тур.	Max.			
A	1.05	1.20	1.35			
A1	0.00	0.10	0.15			
A2	1.00	1.10	1.20			
b	0.30	-	0.50			
b1	0.30	0.35	0.45			
С	0.08	-	0.22			
c1	0.08	0.13	0.20			
D	2.80	2.90	3.00			
E	2.60	2.80	3.00			
E1	1.50	1.60	1.70			
е	0.95 BSC					
e1		1.90 BSC				
L	0.35	0.35 0.43 0.60				
L1		0.60 REF				
L2		0.25 BSC				
R	0.10	-	-			
R1	0.10	-	0.25			
θ	0°	4°	8°			
θ1	5°	6°	15°			
θ2	5°	8°	15°			

Table 4. CT8152 5-Lead SOT23 Package Dimensions

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SOT23-5 Tape & Pocket Drawing and Dimensions



NOTES:

- 1. Material: Conductive Polystyrene
- 2. Dimensions in mm.
- 3. 10 sprocket hole pitch cumulative tolerance ± 0.20 mm.
- 4. Camber bot to exceed 1 mm in 100 mm.
- 5. Pocket position relative to sprocket hole measured as true position of pocket and not pocket hole.
- 6. (S.R. Ω /sq) means surface electric resistivity of the carrier tape.

Figure 40. Tape and Pocket Drawing for 5-lead SOT23 Package

Package Information

Part Number	Package Type	# of Leads	Package Quantity	Lead Finish	Eco Plan ⁽¹⁾	MSL Rating ⁽²⁾	Operating Temperature ⁽³⁾	Device Marking
CT8150PC-IS3	SOT23	3	3,000	Sn	Green & RoHS	1	-40°C to +85°C	MH YWWS
CT8150PC-HS3	SOT23	3	3,000	Sn	Green & RoHS	1	-40°C to +125°C	MH YWWS
CT8150PC-IL4	LGA	4	3,000	Au	Green & RoHS	3	-40°C to +85°C	P YZ
CT8150PC-HL4	LGA	4	3,000	Au	Green & RoHS	3	-40°C to +125°C	P YZ
CT8152PC-IS5	LGA	5	3,000	Au	Green & RoHS	1	-40°C to +85°C	MK YWWS
CT8152PC-HS5	LGA	5	3,000	Au	Green & RoHS	1	-40°C to +125°C	MK YWWS
CT8152PC-IL4	LGA	4	3,000	Au	Green & RoHS	3	-40°C to +85°C	R YZ
CT8152PC-HL4	LGA	4	3,000	Au	Green & RoHS	3	-40°C to +125°C	R YZ

(1) RoHS is defined as semiconductor products that are compliant to the current EU RoHS requirements. It also will meet the requirement that RoHS substances do not exceed 0.1% by weight in homogeneous materials. Green is defined as the content of Chlorine (CI), Bromine (Br) and Antimony Trioxide based flame retardants satisfy JS709B low halogen requirements of ≤ 1,000 ppm.

(2) MSL Rating = Moisture Sensitivity Level Rating as defined by JEDEC standard classifications.

(3) Package will withstand ambient temperature range of -40°C to +150°C and storage temperature range of -65°C to +150°C.

(4) Device Marking for SOT23 is defined as XZ YWWS where XZ = part number, Y = year, WW = work week and S = sequential number. LGA is defined as X where X = part number and YZ = date code information.

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Preliminary	First Production	Data sheet contains preliminary specifications obtained by measurements of early samples. Follow-on data will be published at a later date as more test data is acquired. Crocus reserves the right to make changes to the data sheet at any time.
None	Full Production	Data sheet contains final specifications for all parameters. Crocus reserves the right to make changes to the data sheet at any time.
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Product Status Definition